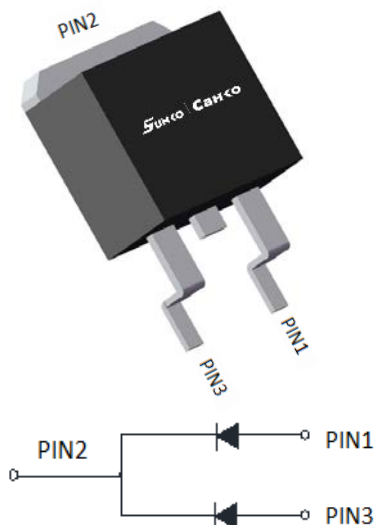


## Schottky Diodes



### Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

### Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

### Mechanical Data

- **Package:** TO-263  
Molding compound meets UL 94 V-0 flammability rating, -
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

### ■Maximum Ratings (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRBL30150CT
Device marking code			MBRBL30150CT
Repetitive Peak Reverse Voltage	VRRM	V	150
Average Rectified Output Current @60Hz sine wave, R-load, T <sub>a</sub> (FIG 1)	I <sub>O</sub>	A	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T <sub>a</sub> =25°C	IFSM	A	220
Current Squared Time @1ms≤t≤8.3ms T <sub>j</sub> =25°C, rating of per diode	I <sup>2</sup> t	A <sup>2</sup> s	200
Storage Temperature	T <sub>stg</sub>	°C	-55 ~ +150
Junction Temperature	T <sub>j</sub>	°C	-55 ~ +150

### ■Electrical Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRBL30150CT
Maximum instantaneous forward voltage drop per diode	VFM	V	IFM=10.0A	0.84
Maximum DC reverse current at rated DC blocking voltage per diode	IRRM1	mA	VRM=VRRM T <sub>a</sub> =25°C	0.1
	IRRM2		VRM=VRRM T <sub>a</sub> =100°C	20

### ■Thermal Characteristics (T<sub>a</sub>=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRBL30150CT
Thermal Resistance Between junction and case	R <sub>θJ-C</sub>	°C/W	2.0

# MBRBL30150CT

## ■Ordering Information (Example)

PREFERED P/N	UNIT WEIGHT(g)	MINIIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRBL30150CT	Approximate 1.43	50	2000	8000	Tube
MBRBL30150CT	Approximate 1.43	1000	2000	10000	Reel

## ■Characteristics (Typical)

FIG1:Io -Tc Curve

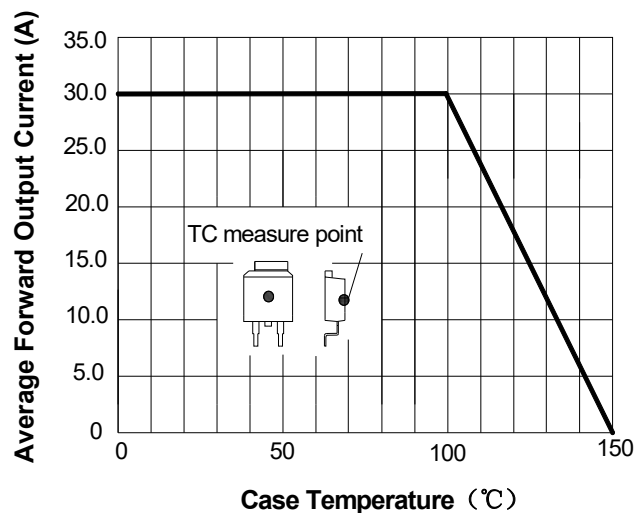


FIG2:Surge Forward Current Capability

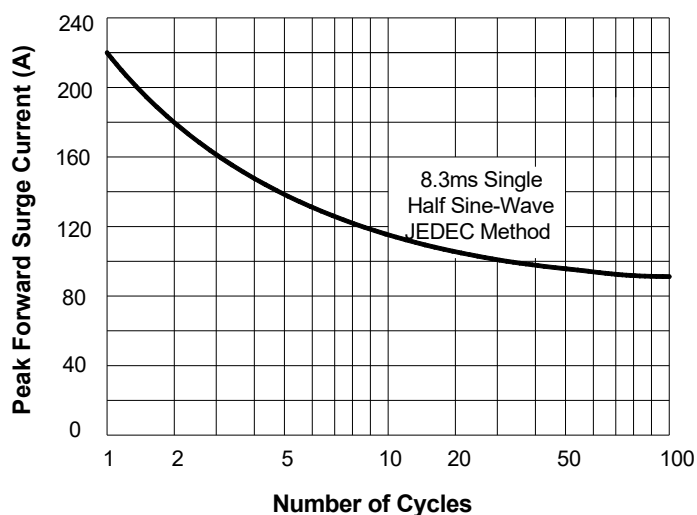


FIG3: Forward Voltage

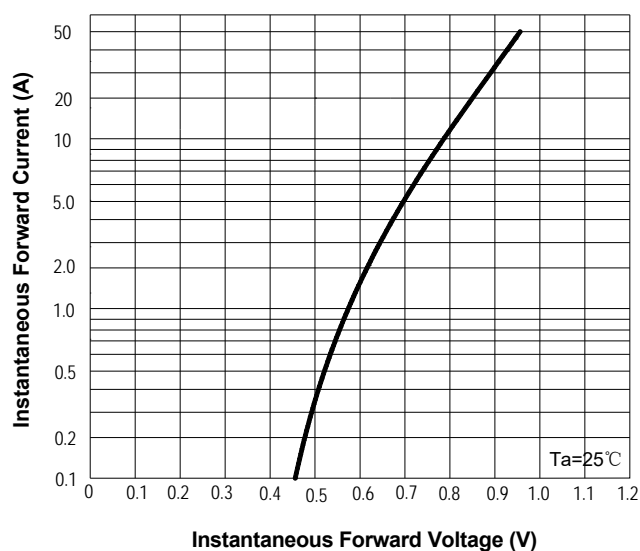
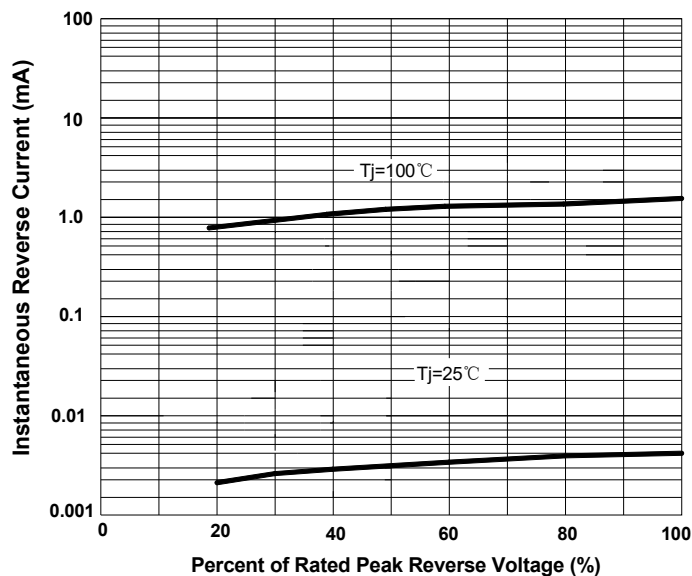
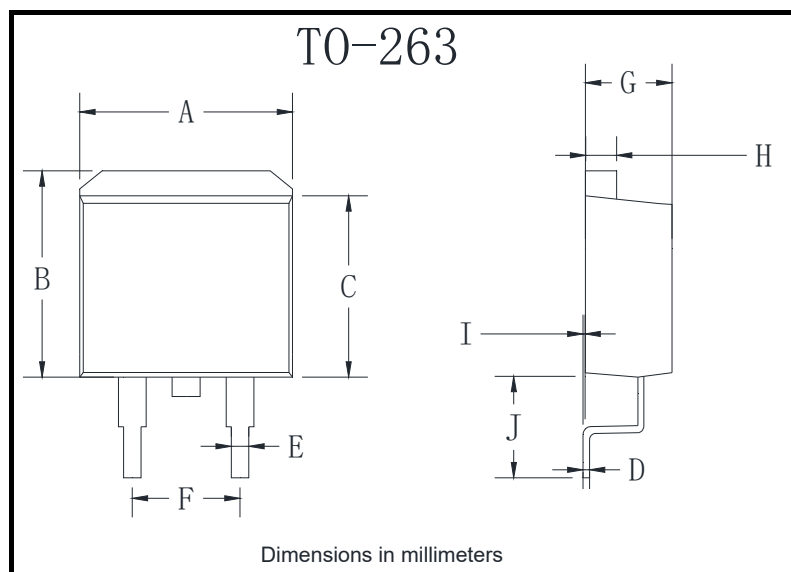


FIG.4: Instantaneous Reverse Characteristics



■ Outline Dimensions



TO-263		
Dim	Min	Max
A	9.5	11.5
B	9.7	10.5
C	8.4	9.0
D	0.28	0.64
E	0.68	0.94
F	4.55	5.6
G	4.04	5.10
H	1.14	1.4
I	0	0.2
J	4.9	6.05

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